

ST13009

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

■ Switch mode power supplies

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability. It uses a hollow emitter structure to enhance switching speeds.

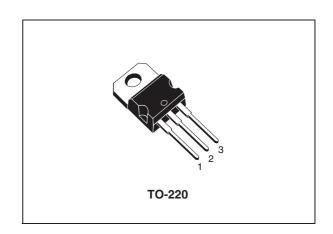


Figure 1. Internal schematic diagram

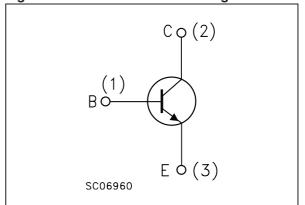


Table 1. Device summary

| Order c | ode | Marking ⁽¹⁾ | Package | Packaging |
|---------|-----|------------------------|---------|-----------|
| ST130 | 09 | 13009 L 13009 H | TO-220 | Tube |

^{1.} Product is pre-selected in DC current gain (group L and group H). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

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ST13009 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|------------------|------------------------------------------------------|------------|------|
| V _{CEV} | Collector-emitter voltage (V _{BE} = -1.5 V) | 700 | V |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | 400 | V |
| V _{EBO} | Emitter-base voltage (I _C = 0) | 12 | V |
| I _C | Collector current | 12 | А |
| I _{CM} | Collector peak current (t _P < 5ms) | 24 | А |
| I _B | Base current | 6 | А |
| I _{BM} | Base peak current (t _P < 5ms) | 12 | А |
| P _{tot} | Total dissipation at T _c = 25°C | 100 | W |
| T _{stg} | Storage temperature | -65 to 150 | °C |
| TJ | Max. operating junction temperature | 150 | °C |

Table 3. Thermal data

| | Symbol | Parameter | Value | Unit |
|---|-----------------------|--------------------------------------|-------|------|
| ĺ | R _{thj-case} | Thermal resistance junction-case Max | 1.25 | °C/W |

Electrical characteristics ST13009

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

| Symbol | Parameter | Test cor | Min. | Тур. | Max. | Unit | |
|-----------------------------------|-----------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------|----------------|------------|---------------------|--------------------------|
| I _{CEV} | Collector cut-off current (V _{BE} = -1.5 V) | V _{CE} = 700 V V _{CE} = 700 V | T _C = 100°C | | | 10 500 | μ Α μ Α |
| I _{EBO} | Emitter cut-off current (I _C = 0) | V _{EB} = 10 V | | | | 10 | μА |
| V _{CEO(sus)} (1) | Collector-emitter sustaining voltage (I _B = 0) | I _C = 10 mA | | 400 | | | V |
| V _{CE(sat)} (1) | Collector-emitter saturation voltage | $I_C = 4 A$ $I_C = 5 A$ $I_C = 8 A$ | $I_B = 0.8 A$ $I_B = 1 A$ $I_B = 1.6 A$ | | | 0.85 0.9 1.25 | V V V |
| | | I _C = 12 A | $I_B = 3 A$ | | | 2.5 | V |
| V _{BE(sat)} (1) | Base-emitter saturation voltage | $I_C = 5 A$ $I_C = 8 A$ | $I_B = 1 A$ $I_B = 1.6 A$ | | | 1.2 1.6 | V V |
| h _{FE} ⁽¹⁾⁽²⁾ | DC current gain | $I_C = 5 A$ Group L Group H $I_C = 8 A$ | $V_{CE} = 5 V$ $V_{CE} = 5 V$ | 15 26 10 | | 31 39 30 | |
| t _s | Inductive load Storage time Fall time | $I_C = 5 A$ $I_{B1} = 1 A$ $L = 200 \mu H$ see Figure 9 | | | 1.6 60 | 2.5 110 | μs ns |
| t _s | Inductive load Storage time Fall time | $I_C = 5 \text{ A}$ $I_{B1} = -I_{B2} = 1.$ $I_{B2} = 1.$ $I_{B3} = 1.$ $I_{B4} = 1.$ $I_{B2} = 1.$ $I_{B4} = 1.$ $I_$ | .6 A | | 2.3 110 | | μs ns |

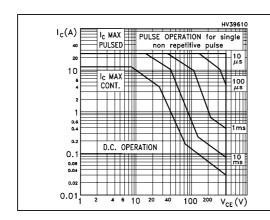
^{1.} Pulsed duration = 300 µs, duty cycle ≤2 %

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2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



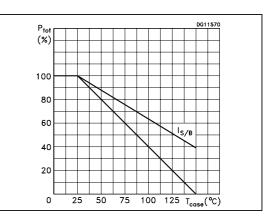
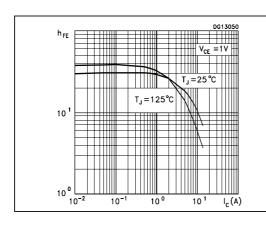


Figure 4. DC current gain

Figure 5. DC current gain



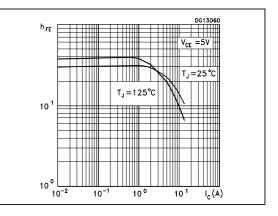
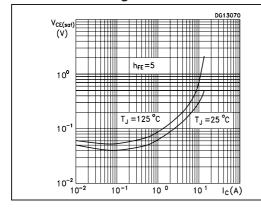
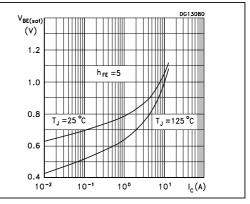


Figure 6. Collector-emitter saturation voltage

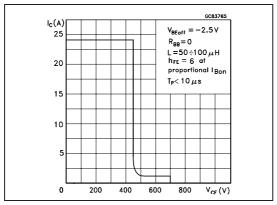
Figure 7. Base-emitter saturation voltage





Electrical characteristics ST13009

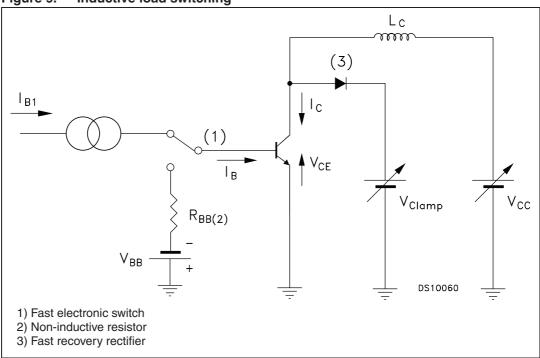
Figure 8. Reverse biased operating area



ST13009 Test circuit

3 Test circuit

Figure 9. Inductive load switching



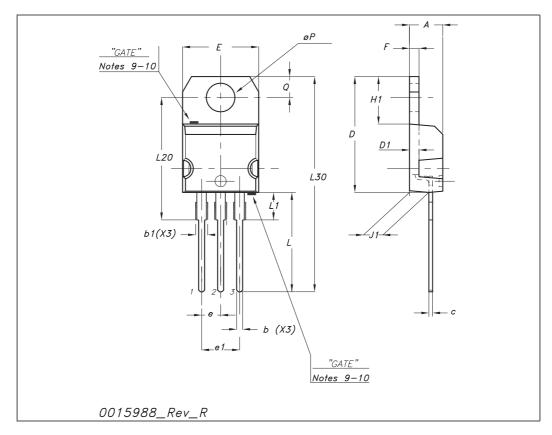
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

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TO-220 mechanical data

| Di | | mm | | | inch | | | |
|-----|-------|-------|-------|-------|-------|-------|--|--|
| Dim | Min | Тур | Max | Min | Тур | Max | | |
| Α | 4.40 | | 4.60 | 0.173 | | 0.181 | | |
| b | 0.61 | | 0.88 | 0.024 | | 0.034 | | |
| b1 | 1.14 | | 1.70 | 0.044 | | 0.066 | | |
| С | 0.48 | | 0.70 | 0.019 | | 0.027 | | |
| D | 15.25 | | 15.75 | 0.6 | | 0.62 | | |
| D1 | | 1.27 | | | 0.050 | | | |
| Е | 10 | | 10.40 | 0.393 | | 0.409 | | |
| е | 2.40 | | 2.70 | 0.094 | | 0.106 | | |
| e1 | 4.95 | | 5.15 | 0.194 | | 0.202 | | |
| F | 1.23 | | 1.32 | 0.048 | | 0.051 | | |
| H1 | 6.20 | | 6.60 | 0.244 | | 0.256 | | |
| J1 | 2.40 | | 2.72 | 0.094 | | 0.107 | | |
| L | 13 | | 14 | 0.511 | | 0.551 | | |
| L1 | 3.50 | | 3.93 | 0.137 | | 0.154 | | |
| L20 | | 16.40 | | | 0.645 | | | |
| L30 | | 28.90 | | | 1.137 | | | |
| ØP | 3.75 | | 3.85 | 0.147 | | 0.151 | | |
| Q | 2.65 | | 2.95 | 0.104 | | 0.116 | | |



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Revision history ST13009

5 Revision history

Table 5. Document revision history

| Date | Revision | Changes | |
|-------------|----------|----------------------------------------------------------------------------------|--|
| 12-Jun-2005 | 1 | First version | |
| 23-Aug-2007 | 2 | Added figures: 2, and 3 | |
| 30-Jun-2009 | 3 | Updated value for h _{FE} see <i>Table 4: Electrical characteristics</i> | |

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